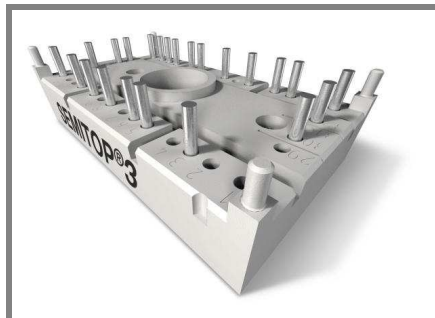


SK35GD065ET



SEMITOP® 3

IGBT Module

SK35GD065ET

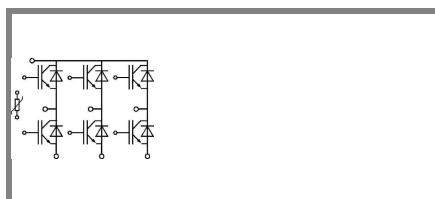
Preliminary Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL technology FWD
- Integrated NTC temperature sensor

Typical Applications*

- Inverter

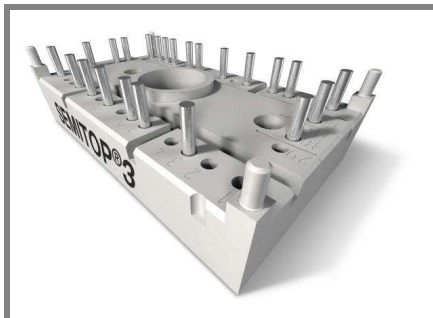


GD-ET

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	Values			Units
IGBT					
V_{CES}	$T_j = 25\text{ °C}$	600			V
I_C	$T_j = 125\text{ °C}$	$T_s = 25\text{ °C}$	45		A
		$T_s = 80\text{ °C}$	33		A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	100			A
V_{GES}		± 20			V
t_{psc}	$V_{CC} = 300\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125\text{ °C}$ $V_{CES} < 600\text{ V}$	10			µs
Inverse Diode					
I_F	$T_j = 150\text{ °C}$	$T_s = 25\text{ °C}$	36		A
		$T_s = 80\text{ °C}$	24		A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$	70			A
Module					
$I_{t(RMS)}$					A
T_{vj}		-40 ... +150			°C
T_{stg}		-40 ... +125			°C
V_{isol}	AC, 1 min.	2500			V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 1\text{ mA}$	3	4	5	V
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$			mA
		$T_j = 125\text{ °C}$			mA
I_{GES}	$V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V}$	$T_j = 25\text{ °C}$	120		nA
		$T_j = 125\text{ °C}$			nA
V_{CE0}		$T_j = 25\text{ °C}$	1,2	1,3	V
		$T_j = 125\text{ °C}$	1,1	1,2	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	16	24	mΩ
		$T_j = 125\text{ °C}$	22	30	mΩ
$V_{CE(sat)}$	$I_{Cnom} = 50\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	2	2,5	V
		$T_j = 125\text{ °C}_{chiplev.}$	2,2		V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	2,7		nF
C_{oes}			0,25		nF
C_{res}			0,153		nF
$t_{d(on)}$	$R_{Gon} = 15\text{ } \Omega$	$V_{CC} = 300\text{ V}$ $I_C = 50\text{ A}$	35		ns
t_r			35		ns
E_{on}			1,3		mJ
$t_{d(off)}$	$R_{Goff} = 15\text{ } \Omega$	$T_j = 125\text{ °C}$ $V_{GE} = \pm 15\text{ V}$	240		ns
t_f			25		ns
E_{off}			0,6		mJ
$R_{th(j-s)}$	per IGBT	1			K/W

SK35GD065ET



SEMITOP[®] 3

IGBT Module

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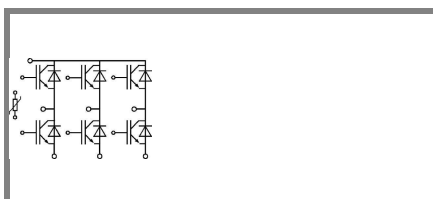
Preliminary Data

Features

- Compact design
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- Ultrafast NPT technology IGBT
- CAL technology FWD
- Integrated NTC temperature sensor

Typical Applications*

- Inverter

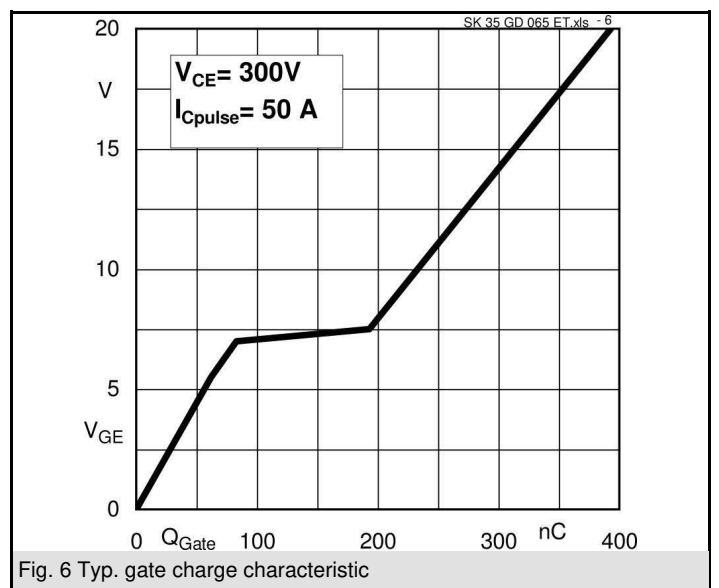
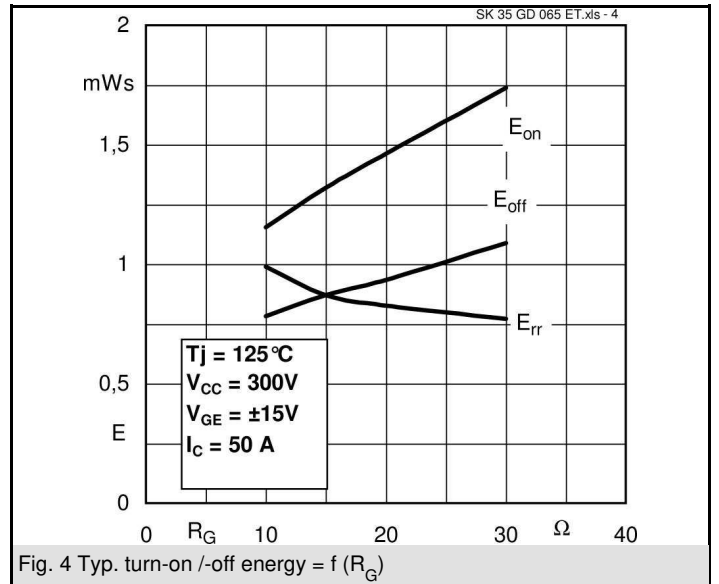
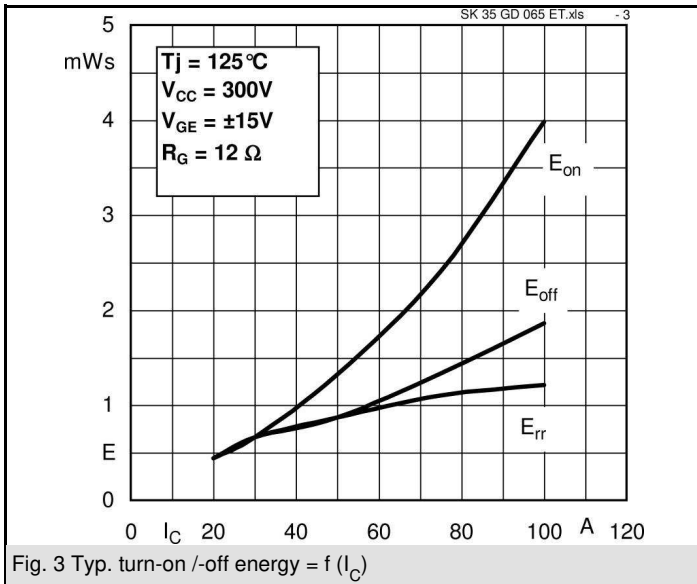
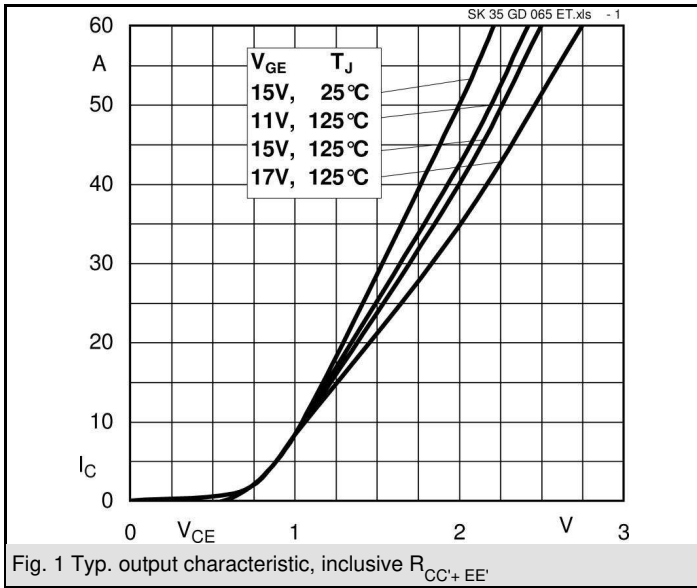


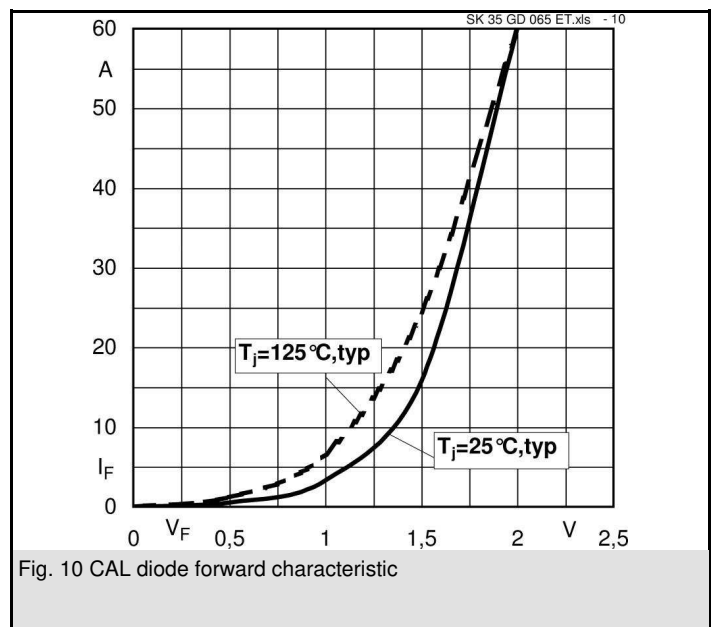
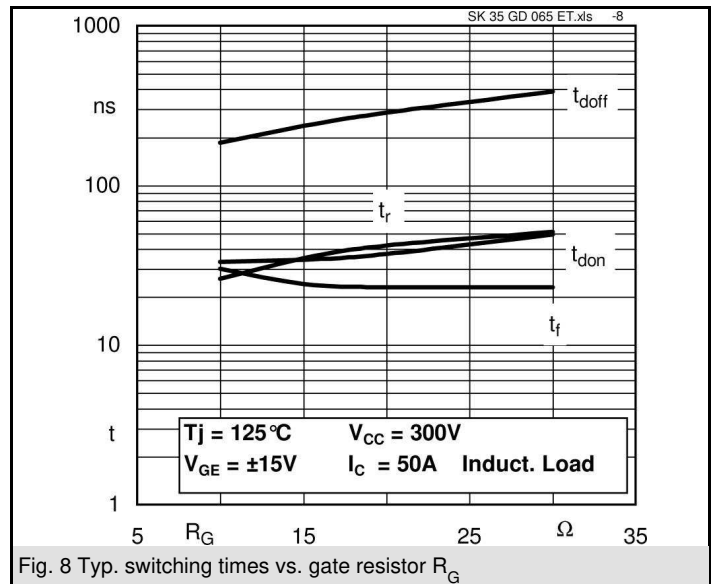
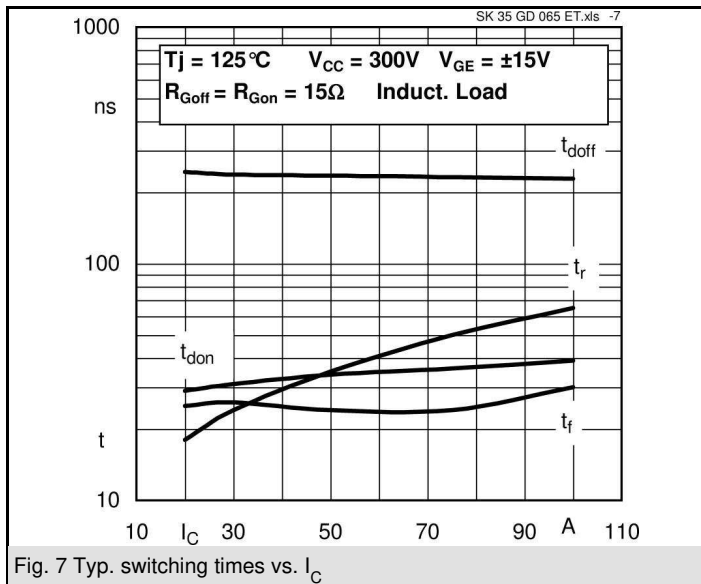
GD-ET

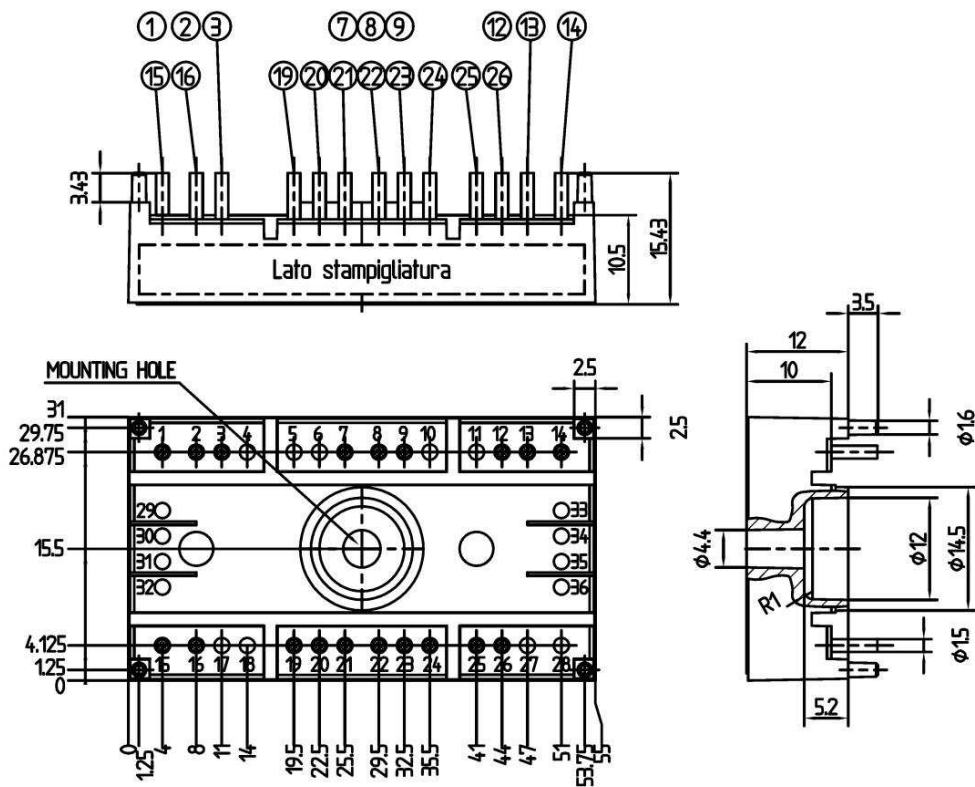
Characteristics			min.	typ.	max.	Units
Symbol	Conditions					
Inverse Diode						
$V_F = V_{EC}$	$I_{Fnom} = 50 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$		1,9	2,3	V
		$T_j = 125 \text{ }^\circ\text{C}_{\text{chiplev.}}$		1,9	2,4	V
V_{F0}		$T_j = 25 \text{ }^\circ\text{C}$		1	1,1	V
		$T_j = 125 \text{ }^\circ\text{C}$		0,9		V
r_F		$T_j = 25 \text{ }^\circ\text{C}$		18	24	m Ω
		$T_j = 125 \text{ }^\circ\text{C}$		20	28	m Ω
I_{RRM}	$I_F = 50 \text{ A}$	$T_j = 125 \text{ }^\circ\text{C}$		57		A
Q_{rr}	$di/dt = -2400 \text{ A}/\mu\text{s}$			4,6		μC
E_{rr}	$V_{CC} = 300\text{V}$			0,9		mJ
$R_{th(j-s)D}$	per diode				1,7	K/W
M_s	to heat sink		2,25		2,5	Nm
w				30		g
Temperature sensor						
R_{100}	$T_s = 100^\circ\text{C}$ ($R_{25} = 5\text{k}\Omega$)			493 \pm 5%		Ω

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.







Case T52 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)

